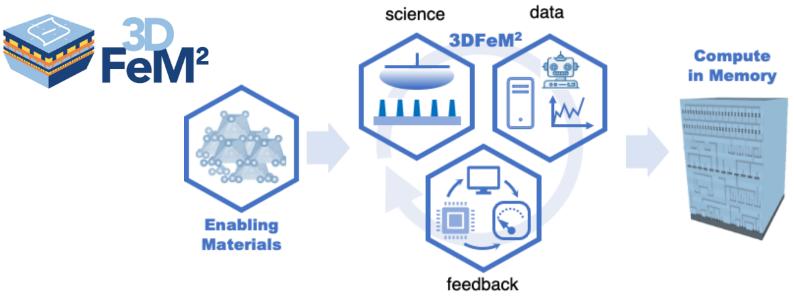
Center for 3 Dimensional Ferroelectric Microelectronics Manufacturing (3DFeM²) Susan Trolier-McKinstry (The Pennsylvania State University); Class: 2020-2028

MISSION: To integrate reliable, scaled ferroelectric films for 3D memory using next generation manufacturing practices.

Autonomous experiments and machine learning (ML) will expedite optimization; digital twins accelerate innovation through virtual experiments.



RESEARCH PLAN: 3DFeM² will *i.* understand crystal chemistry design rules and boundary conditions that regulate ferroelectricity, *ii.* control ferroelectricity-enabling and lifetime-limiting defects in next-generation ferroelectrics, *iii.* identify descriptors for defect chemistry, structure, and property evolution during processing, *iv.* utilize ML and *in situ* microscopy to identify phases, switching mechanisms, and scaling trends, *v.* enable autonomous workflows for 3D film growth and etching, *vi.* generate novel device concepts, and *vii.* establish predictive digital twins based on device configuration, manufacturing process history and system-level operation.



















